# BCS65S06D3

# Silicon Carbide Schottky Diode

650V, 6A



#### **Description**

BCS65S06D3 utilizes Bestirpower's advanced silicon carbide diode technology. This technology combines the benefits of excellent low forward voltage and robustness. Consequently, the family is suitable for application requiring high power efficiency

#### **Benefits**

- High frequency
- Low heat dissipation requirements
- Reduce size and cost of the system
- High-reliability

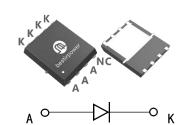
#### **Applications**

- SMPS
- Solar inverter
- Data Center
- Uninterruptible power supply

#### **Features**

$V_{RRM}$	I <sub>F</sub>	T <sub>c</sub>	Q <sub>C</sub>
650 V	6 A	153℃	19 nC

- Negligible reverse recovery
- High Surge current
- Positive Temperature Coefficient
- Higher frequency
- RoHS compliant / Halogen-free







### **Absolute Maximum Ratings** (T<sub>C</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Value	Unit	
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage		650	V
I <sub>F</sub>	Forward Current	T <sub>C</sub> = 25°C	17	А
		T <sub>C</sub> = 141°C	9	А
		T <sub>C</sub> = 153°C	6	А
I <sub>F,SM</sub>	Non-Repetitive Forward Surge Current	$T_C = 25^{\circ}C$ , $t_p = 10 \text{ ms}$	49	А
		$T_C = 110^{\circ}C$ , $t_p = 10 \text{ ms}$	43	А
I <sub>F,RM</sub>	Repetitive Peak Forward Surge Current	Tc = 25°C, tp = 10 ms	38	А
l <sup>2</sup> dt value	∫l²t	$T_C = 25^{\circ}C$ , $t_p = 10 \text{ ms}$	13	A <sup>2</sup> s
		$T_C = 110^{\circ}C$ , $t_p = 10 \text{ ms}$	10	A <sup>2</sup> s
P <sub>tot</sub>	Power Dissipation	T <sub>C</sub> = 25°C	69	W
		T <sub>C</sub> = 110°C	30	W
		T <sub>C</sub> = 150°C	12	W
$T_J, T_{STG}$	Operating Junction and Storage Temperature		-55 to +175	℃



## **Thermal Characteristics**

Symbol	Parameter	Value	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Typ.	2.17	°C/W

# **Electrical Characteristics** (T<sub>C</sub> = 25°C unless otherwise noted)

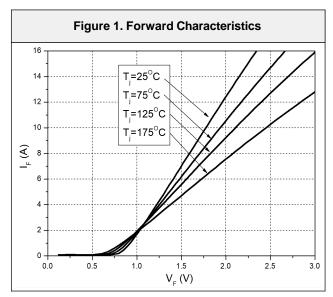
Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit	
V <sub>DC</sub>	DC blocking voltage		650			V	
V <sub>F</sub> Foi	Forward Voltage	I <sub>F</sub> =6A,T <sub>J</sub> =25℃	-	1.4	1.7		
		I <sub>F</sub> =6A,T <sub>J</sub> =175℃	-	1.7	-	V	
I <sub>R</sub> R	Reverse Current	V <sub>R</sub> = 650 V, T <sub>J</sub> = 25°C	-	2	20	μΑ	
		V <sub>R</sub> = 650 V, T <sub>J</sub> = 175°C	-	40	-		
Q <sub>C</sub>	Total Capacitive Charge	V <sub>R</sub> = 400 V, T <sub>J</sub> = 25°C	-	19	-	nC	
C Total Ca	Total Conscitours	V <sub>R</sub> = 0 V, f = 1MHz	-	386	-		
	Total Capacitance	V <sub>R</sub> = 200 V, f = 1MHz	-	37	-	pF	
		V <sub>R</sub> = 400 V, f = 1MHz	-	29	-	'	
Ec	Capacitance Stored Energy	V <sub>R</sub> = 400 V, T <sub>C</sub> = 25°C	-	5.0	-	μJ	

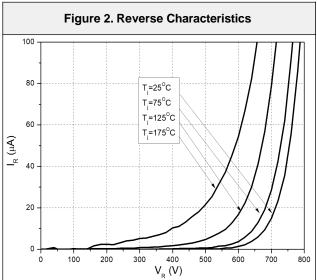
# **Package Marking and Ordering Information**

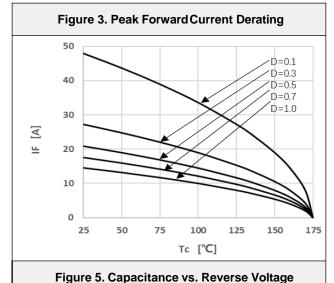
Part Number	Top Marking	Package	Packing Method	Quantity
BCS65S06D3	BCS65S06D3	DFN5*6	Tape & Reel	5000 units

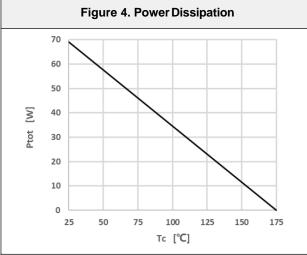


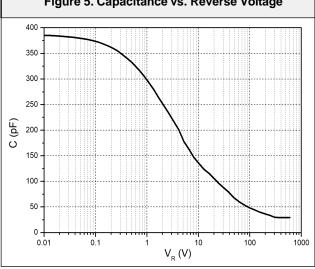
#### **Typical Performance Characteristics**

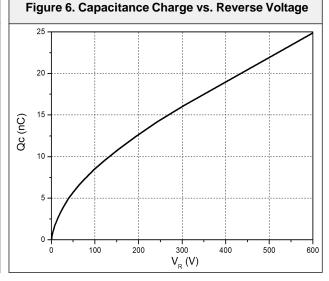








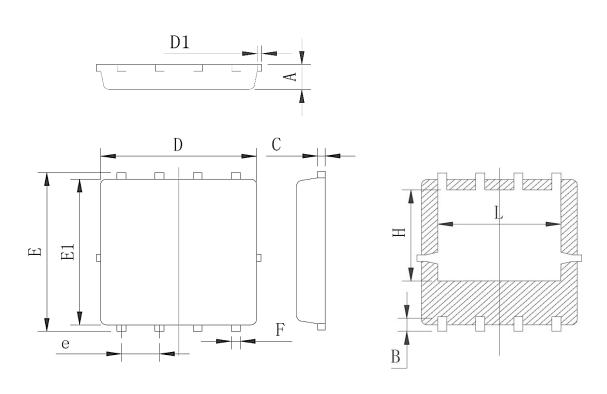






# **Package Outlines**

# **DFN 5\*6**



Symbol	Min	Тур	Max
A	0.90	0.95	1.00
В	0.48	0.58	0.68
С	0.20	0.254	0.30
D	5.00	5.20	5.40
D1			0.15
Е	5.90	6.05	6.20
E1	5.40	5.55	5.70
e	1.22	1.27	1.32
F	0.25	0.30	0.35
Н	3.27	3.47	3.67
L	3.80	4.00	4.20



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